

Features

- Split Gate Trench MOSFET technology
- Excellent Package for Heat Dissipation
- High Density Cell Desihn for Low $R_{DS(on)}$
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

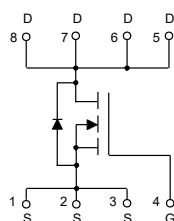
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 55°C/W Junction to Ambient^(Note 2)
- Thermal Resistance: 1.2°C/W Junction to Case

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V _{DS}	60	V
Gate-Source Voltlage		V _{GS}	±20	V
Drain Current		I _D	130	A
Continuous Drain Current ^(Note 3)	T _C =25°C	I _D	85	A
	T _C =100°C		54	A
Pulsed Drain Current ^(Note 4)		I _{DM}	390	A
Single Pulse Avalanche Energy ^(Note 5)		E _{AS}	270	mJ
Total Power Dissipation ^(Note 6)		P _D	105	W

Note:

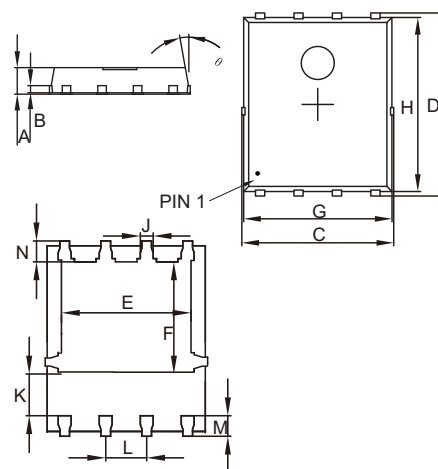
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The Value of $R_{\theta JA}$ is Measured with the Device Mounted on 1 in² FR-4 Board with 2oz. Copper, in a Still Air Environment with $T_A=25^\circ\text{C}$.
3. The Maximum Current Rating is Package Limited.
4. Pulse Width Limited by Max. Junction Temperature.
5. $V_{DD}=50\text{ V}$, $R_G=25\ \Omega$, $L=0.5\text{mH}$, starting $T_J=25^\circ\text{C}$.
6. PD is Based on Max. Junction Temperature, Using Junction-Case Thermal Resistance.

Internal Structure



N-CHANNEL MOSFET

DFN5060



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.031	0.047	0.80	1.20	
B	0.010		0.254		TYP.
C	0.193	0.222	4.90	5.64	
D	0.232	0.250	5.90	6.35	
E	0.148	0.167	3.75	4.25	
F	0.126	0.154	3.20	3.92	
G	0.189	0.213	4.80	5.40	
H	0.222	0.239	5.65	6.06	
K	0.045	0.059	1.15	1.50	
J	0.012	0.020	0.30	0.50	
L	0.046	0.054	1.17	1.37	
M	0.012	0.028	0.30	0.71	
N	0.016	0.028	0.40	0.71	

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	60			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$			1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	1.8	2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=20A$		2.5	3	m Ω
		$V_{GS}=4.5V, I_D=10A$		3.5	4.5	
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=20A$			1.2	V
Continuous Body Diode Current	I_S				85	A
Dynamic Characteristics^(Note 7)						
Input Capacitance	C_{iss}	$V_{DS}=30V, V_{GS}=0V, f=1MHz$		3350		pF
Output Capacitance	C_{oss}			1666		
Reverse Transfer Capacitance	C_{rss}			77.7		
Total Gate Charge	Q_g	$V_{DS}=30V, V_{GS}=10V, I_D=25A$		66.1		nC
Gate-Source Charge	Q_{gs}			10.7		
Gate-Drain Charge	Q_{gd}			10.9		
Reverse Recovery Charge	Q_{rr}	$I_S=25A, di/dt=100A/\mu s$		73		
Reverse Recovery Time	t_{rr}			68		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V, V_{DD}=30V, I_D=25A$ $R_{GEN}=2\Omega$		22.5		ns
Turn-On Rise Time	t_r			6.7		
Turn-Off Delay Time	$t_{d(off)}$			80.3		
Turn-Off Fall Time	t_f			26.9		

Note 7. Guaranteed by Design, Not Subject to Production Testing.

Curve Characteristics

Fig. 1 - Typical Output Characteristics

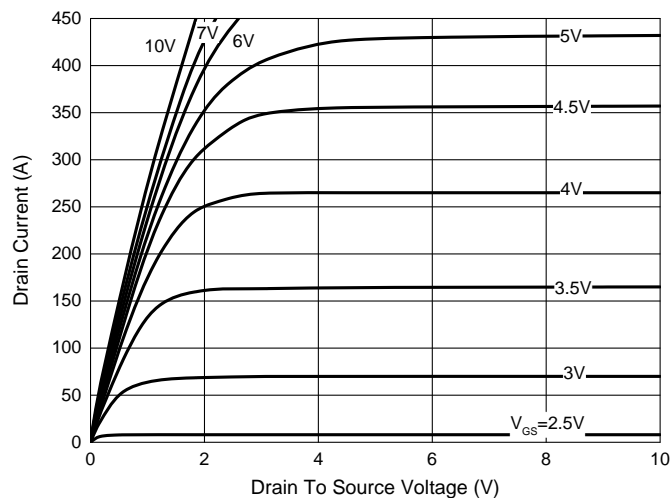


Fig. 2 - Drain-Source Breakdown Voltage

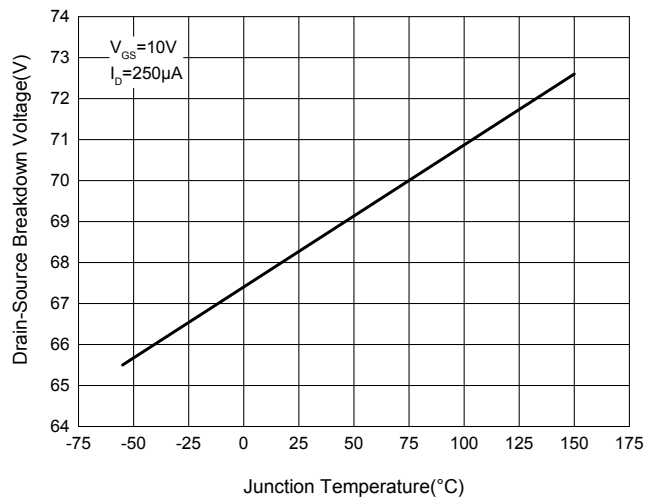


Fig. 3 - Capacitance Characteristics

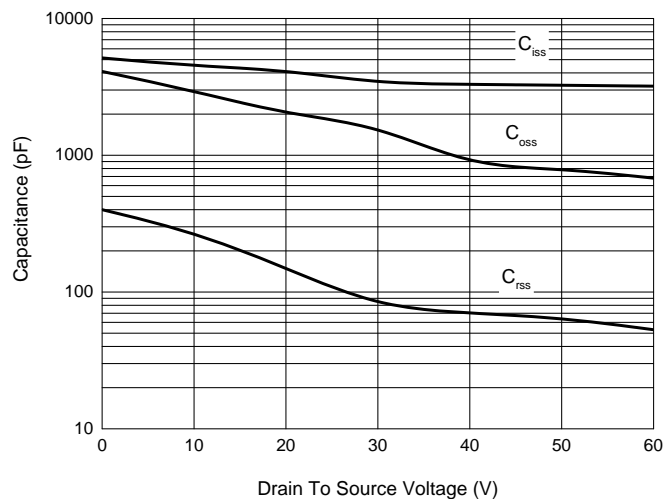


Fig. 4 - Gate Charge Characteristics

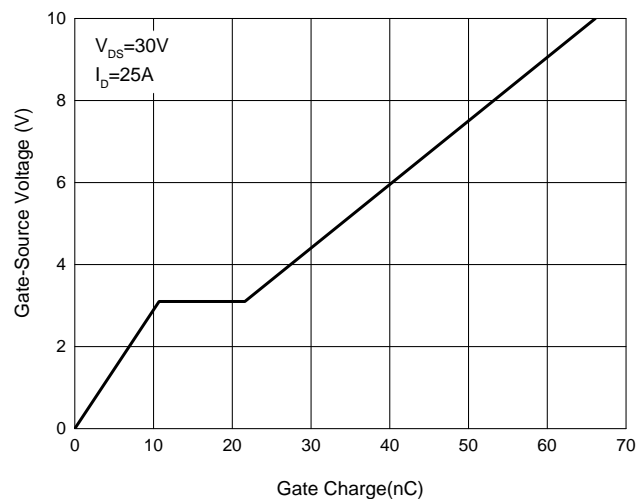


Fig. 5 - On Resistance Characteristics

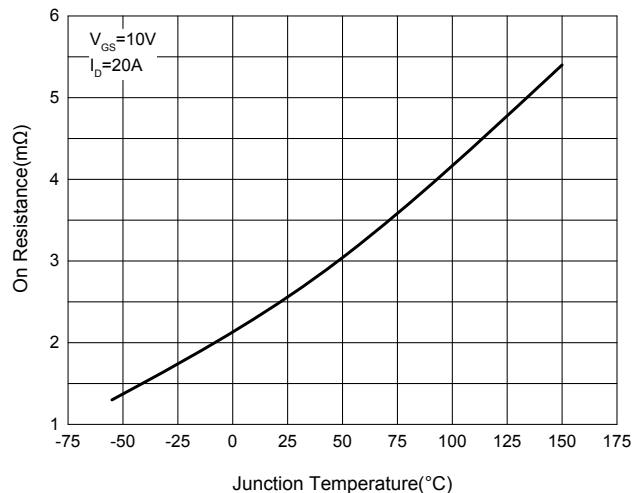
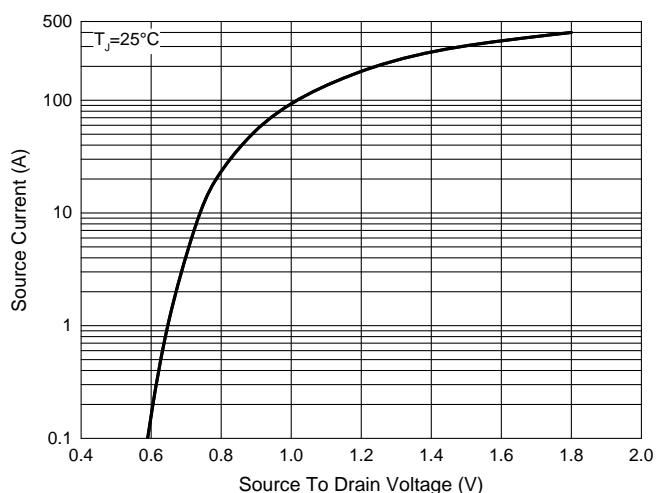


Fig. 6 - $I_S - V_{SD}$



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

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